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APPLICATION NO.	PPLICATION NO. FILING DATE FIRST		ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/813,786 03/30/2004		Ching-Chen Hao	67,200-1071	5208	
7590 04/05/2005 TUNG & ASSOCIATES 838 W. Long Lake Road, Suite 120			EXAMINER NGUYEN, CUONG QUANG		
			2811		
			DATE MAILED: 04/05/2005		

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application	n No.	Applicant(s)			
Office Action Summary		10/813,78	6	HAO ET AL.			
		Examiner		Art Unit			
		Cuong Q.	_ <del></del>	2811			
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply							
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.  - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.  - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133).  Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).							
Status							
1)	Responsive to communication(s) filed o	n					
2a) <u></u> □	This action is FINAL. 2b)	This action is not action is not action.	on-final.				
3) 🗌	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.						
Dispositi	on of Claims						
5)⊠ 6)⊠	4) ☐ Claim(s) 1-18 is/are pending in the application.  4a) Of the above claim(s) is/are withdrawn from consideration.  5) ☐ Claim(s) 8-18 is/are allowed.  6) ☐ Claim(s) 1-7 is/are rejected.  7) ☐ Claim(s) is/are objected to.  8) ☐ Claim(s) are subject to restriction and/or election requirement.						
Applicati	on Papers						
9)	The specification is objected to by the Ex	xaminer.					
10)	10) ☐ The drawing(s) filed on is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.						
	Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).						
11)	Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).  11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.						
Priority u	ınder 35 U.S.C. § 119						
<ul> <li>12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).</li> <li>a) All b) Some * c) None of:</li> <li>1. Certified copies of the priority documents have been received.</li> <li>2. Certified copies of the priority documents have been received in Application No</li> <li>3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).</li> <li>* See the attached detailed Office action for a list of the certified copies not received.</li> </ul>							
2) Notice Notice Notice	t(s) e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (PTO- nation Disclosure Statement(s) (PTO-1449 or PTC r No(s)/Mail Date		4) Interview Summary Paper No(s)/Mail D 5) Notice of Informal I 6) Other:	ate	O-152)		

#### **DETAILED ACTION**

## Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless --

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 1, 2, 4, 5, 6 are rejected under 35 U.S.C. 102(b) as being anticipated by Mikata et al. (US 6,713,824).

Mikata et al. discloses a method for forming a gate dielectric layer comprising: providing a silicon semiconductor substrate (121); thermally oxidizing the semiconductor substrate within a thermal oxidizing atmosphere comprising a halogen getter material (a hydrogen chloride halogen HCl material) to form a gate dielectric layer (122) upon a thermally oxidized semiconductor substrate, wherein the gate dielectric layer formed from a non-nitrided silicon oxide material. See Fig.2.

Claims 1, 2, 4, 5, 6, 7 are rejected under 35 U.S.C. 102(b) as being anticipated by Suzuki et al. (US 5,506,178).

Suzuki et al. discloses a method for forming a gate dielectric layer comprising: providing a silicon semiconductor substrate (10); wet thermal oxidizing the

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semiconductor substrate within a thermal oxidizing atmosphere comprising a halogen getter material (a hydrogen chloride halogen HCl material) to form a gate dielectric layer (14) upon a thermally oxidized semiconductor substrate, wherein the gate dielectric layer formed from a non-nitrided silicon oxide material. See abstract and Fig.1A to Fig.1C.

## Claim Rejections - 35 USC § 103

2. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claim 3 is rejected under 35 U.S.C. 103(a) as being unpatentable over Mikata et al. or Suzuki et al in view of Dokumaci et al. (US 6,586,289).

Mikata et al. and Suzuki et al. teach all the limitation of claim 1 as shown above. However, these references do not explicitly teach that the substrate is a SiGe alloy substrate.

It is conventional and also taught by Dokumaci et al. that silicon and silicon germanium alloy are art recognized materials for forming the semiconductor substrate and they are interchangeable. See Dokumaci et al.'s col.4 lines 15-20.

It would have been obvious to one of ordinary skill in the art to form the semiconductor substrate of silicon germanium alloy instead of silicon as suggested by Dokumaci et al.

### **Allowable Subject Matter**

- 3. Claims 8- 18 are allowed.
- 4. The following is an examiner's statement of reasons for allowance: Mikata et al. and Suzuki et al. appear to be the closest prior art reference. However, these reference fails to teach a method for forming a gate dielectric layer comprises all the steps as claimed in claim 8. Prior art of record fails to teach or suggest to incorporate these limitations into Mikata et al. and Suzuki et al. to arrive at the claimed device.

#### Conclusion

- 5. Papers related to this application may be submitted to Technology center (TC) 2800 by facsimile transmission. Papers should be faxed to TC 2800 via the TC 2800 Fax center located in Crystal Plaza 4, room 4-C23. The faxing of such papers must conform with the notice published in the Official Gazette, 1096 OG 30 (November 15, 1989). The Group 2811 Fax Center number is (703) 872-9306. The Group 2811 Fax Center is to be used only for papers related to Group 2811 applications.
- 6. Any inquiry concerning this communication or any earlier communication from the Examiner should be directed to CUONG Q NGUYEN whose telephone number is

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(571) 272-1661. The Examiner is in the Office generally between the hours of 6:30 AM

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to 5:00 PM (Eastern Standard Time) Monday through Thursday.

7. If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor Eddie Lee who can be reached on (571) 272-1732.

8. Any inquiry of a general nature or relating to the status of this application should

be directed to the Technology Center Receptionists whose telephone number is 308-

0956.

Cuona Nguyen

Primary examiner

4/3/05